

# Thyristor High Voltage, Phase Control SCR, 30 A



PRIMARY CHARACTERISTICS						
I <sub>T(AV)</sub> 20 A						
V <sub>DRM</sub> /V <sub>RRM</sub>	1600 V					
V <sub>TM</sub>	1.3 V					
I <sub>GT</sub>	45 mA					
TJ	-40 °C to +125 °C					
Package	TO-247AD 3L					
Circuit configuration	Single SCR					

### **FEATURES**

- Designed and qualified according to JEDEC® - JESD 47
- Flexible solution for reliable AC power rectification



- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

#### **DESCRIPTION**

The VS-30TPS16L-M3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. AEC-Q101 qualified P/N available (VS-30TPS16LHM3).

PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I <sub>T(AV)</sub>	Sinusoidal waveform	20	^	
I <sub>RMS</sub>		30	A	
V <sub>RRM</sub> /V <sub>DRM</sub>		1600	V	
I <sub>TSM</sub>		300	А	
$V_{T}$	20 A, T <sub>J</sub> = 25 °C	1.3	V	
dv/dt		500	V/µs	
di/dt		150	A/µs	
TJ		-40 to +125	°C	

VOLTAGE RATINGS							
PART NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA				
VS-30TPS16L-M3	1600	1700	10				



ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum average on-state current	I <sub>T(AV)</sub>	T <sub>C</sub> = 95 °C, 180° conduction	half sine wave	20		
Maximum RMS on-state current	I <sub>RMS</sub>			30	Α	
Maximum peak, one-cycle,	l	10 ms sine pulse, rated V <sub>RRM</sub>	applied	250	Α	
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage	reapplied	300		
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub>	applied	310	A <sup>2</sup> s	
	1-1	10 ms sine pulse, no voltage reapplied		442	A-5	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied		4420	A <sup>2</sup> √s	
Maximum on-state voltage drop	$V_{TM}$	20 A, T <sub>J</sub> = 25 °C		1.3	V	
On-state slope resistance	r <sub>t</sub>	T 405 00		12	mΩ	
Threshold voltage	V <sub>T(TO)</sub>	T <sub>J</sub> = 125 °C		1.0	V	
Maximum reverse and direct leakage current	I <sub>RM</sub> /I <sub>DM</sub>	$T_J = 25  ^{\circ}C$	V <sub>R</sub> = rated V <sub>RRM</sub> /V <sub>DRM</sub>	0.5		
waxiinaiii reverse and direct leakage current	'RM/ 'DM	T <sub>J</sub> = 125 °C	VR - rated VRRM/ VDRM	10	mA	
Maximum holding current	lΗ	Anode supply = 6 V, resistive load, initial $I_T$ = 1 A, $T_J$ = 25 $^{\circ}$ C		150	ША	
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T <sub>J</sub> = 25 °C		200		
Maximum rate of rise of off-state voltage	dv/dt	$T_J = T_J$ maximum, linear to 80 % $V_{DRM}$ , $R_g$ - $k$ = open		500	V/µs	
Maximum rate of rise of turned-on current	di/dt			150	A/μs	

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P <sub>GM</sub>		8.0	W	
Maximum average gate power	P <sub>G(AV)</sub>		2.0	VV	
Maximum peak positive gate current	+I <sub>GM</sub>		1.5	Α	
Maximum peak negative gate voltage	-V <sub>GM</sub>		10	V	
	I <sub>GT</sub>	Anode supply = 6 V, resistive load, T <sub>J</sub> = -10 °C	60		
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J = 25$ °C	45	mA	
		Anode supply = 6 V, resistive load, T <sub>J</sub> = 125 °C	20		
Manifesture respected DC and		Anode supply = 6 V, resistive load, T <sub>J</sub> = -10 °C	2.5		
Maximum required DC gate voltage to trigger	$V_{GT}$	Anode supply = 6 V, resistive load, T <sub>J</sub> = 25 °C	2.0	.,	
voltage to trigger		Anode supply = 6 V, resistive load, $T_J = 125$ °C	1.0	V	
Maximum DC gate voltage not to trigger	$V_{GD}$	T 405 % V	0.25		
Maximum DC gate current not to trigger	I <sub>GD</sub>	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = rated value		mA	

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Typical turn-on time	t <sub>gt</sub>	T <sub>J</sub> = 25 °C	0.9			
Typical reverse recovery time	t <sub>rr</sub>	T <sub>.l</sub> = 125 °C	4	μs		
Typical turn-off time	t <sub>q</sub>	IJ = 125 C	110			



THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to 125	°C	
Maximum thermal resistance, junction to case		$R_{thJC}$	DC operation	0.8		
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>	DO OPERATION	40	°C/W	
Maximum thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.25		
Approximate weight				6	g	
Approximate weight				0.21	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Modifility torque	maximum			12 (10)	(lbf · in)	
Marking device			Case style TO-247AD 3L	30TP	S16L	

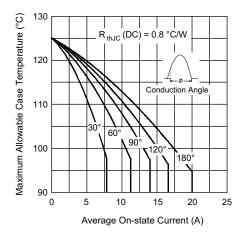


Fig. 1 - Current Rating Characteristics

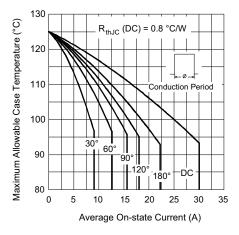


Fig. 2 - Current Rating Characteristics

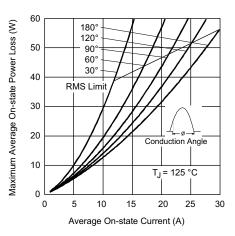


Fig. 3 - On-State Power Loss Characteristics

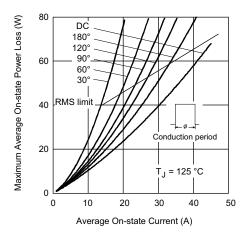


Fig. 4 - On-State Power Loss Characteristics



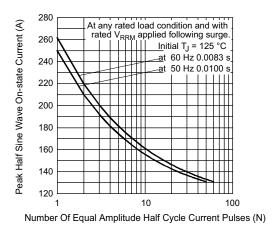


Fig. 5 - Maximum Non-Repetitive Surge Current

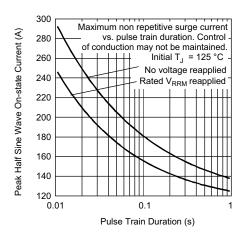


Fig. 6 - Maximum Non-Repetitive Surge Current

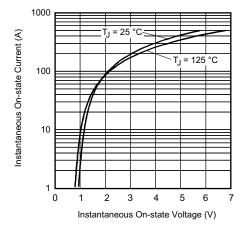


Fig. 7 - On-State Voltage Drop Characteristics

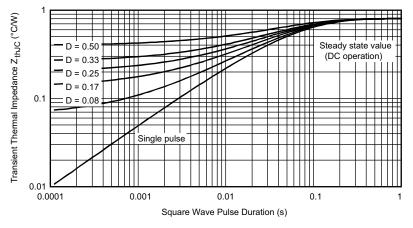


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics



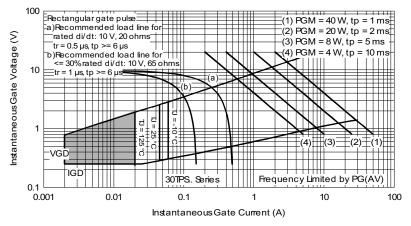
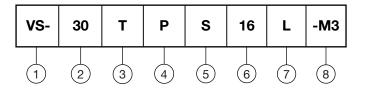


Fig. 9 - Gate Characteristics

### **ORDERING INFORMATION TABLE**

### **Device code**



1 - Vishay Semiconductors product

2 - Current rating (30 = 30 A)

3 - Circuit configuration:

T = thyristor

4 - Package:

P = TO-247

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Package L = long lead

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

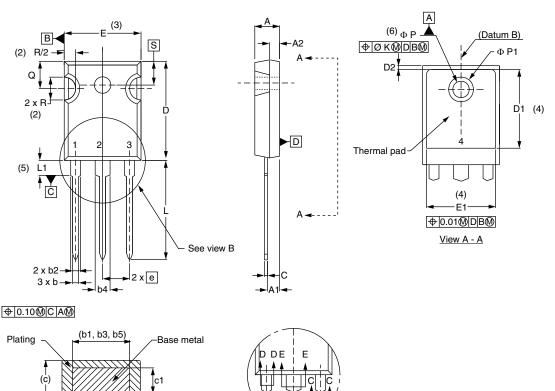
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-30TPS16L-M3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95626</u>				
Part marking information	www.vishay.com/doc?95007			



### **TO-247AD 3L**

### **DIMENSIONS** in millimeters and inches



View B

	MILLIMETERS INCHES					
SYMBOL	IVIILLIIV	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.65	5.31	0.183	0.209		
A1	2.21	2.59	0.087	0.102		
A2	1.50	2.49	0.059	0.098		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.34	0.065	0.092		
b4	2.59	3.43	0.102	0.135		
b5	2.59	3.38	0.102	0.133		
С	0.38	0.89	0.015	0.035		
c1	0.38	0.84	0.015	0.033		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	

Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	INCHES		
OTIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.30	0.020	0.051		
E	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØΚ	0.254		0.0	)10		
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51	BSC	0.217	BSC		

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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